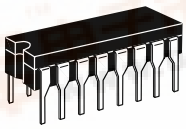
MC14530B

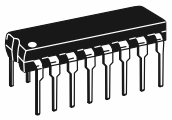
Dual 5-Input Majority Logic Gate

The MC14530B dual five–input majority logic gate is constructed with P–channel and N–channel enhancement mode devices in a single monolithic structure. Combinational and sequential logic expressions are easily implemented with the majority logic gate, often resulting in fewer components than obtainable with the more basic gates. This device can also provide numerous logic functions by using the W and some of the logic (A thru E) inputs as control inputs.

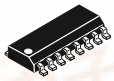
- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–power Schottky TTL Load Over the Rated Temperature Range



L SUFFIX
CERAMIC
CASE 620



P SUFFIX
PLASTIC
CASE 648



D SUFFIX
SOIC
CASE 751B

ORDERING INFORMATION

MC14XXXBCP	Plastic
MC14XXXBCL	Ceramic
MC14XXXBD	SOIC

T_A = – 55° to 125°C for all packages.

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	– 0.5 to + 18.0	V
V_{in}, V_{out}	Input or Output Voltage (DC or Transient)	– 0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
P_D	Power Dissipation, per Package†	500	mW
T_{stg}	Storage Temperature	– 65 to + 150	°C
T_L	Lead Temperature (8–Second Soldering)	260	°C

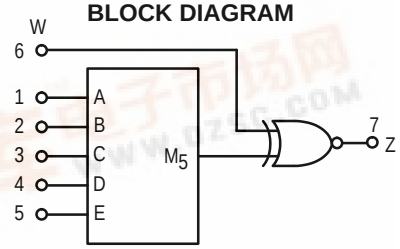
* Maximum Ratings are those values beyond which damage to the device may occur.
†Temperature Derating:
Plastic “P and D/DW” Packages: – 7.0 mW/°C From 65°C To 125°C
Ceramic “L” Packages: – 12 mW/°C From 100°C To 125°C

LOGIC TABLE

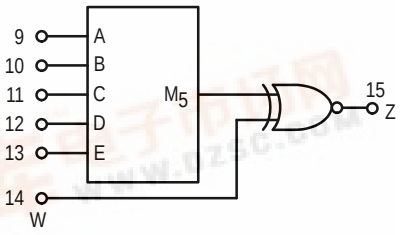
INPUTS A B C D E	W	Z
For all combinations of inputs where three or more inputs are logical “0”.	0	1
	1	0
For all combinations of inputs where three or more inputs are logical “1”.	0	0
	1	1

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in}$ or $V_{out}) \le V_{DD}$.
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

BLOCK DIAGRAM



* $Z = M_5 \odot W = (ABC+ABD+ABE+ACD+ACE+ADE+BCD+BCE+BDE+CDE) \odot W$



* M_5 is a logical “1” if any three or more inputs are logical “1”.

$\odot \equiv$ Exclusive NOR $\equiv \overline{\text{Exclusive OR}}$

TRUTH TABLE

M_5	W	Z
0	0	1
0	1	0
1	0	0
1	1	1

V_{DD} = PIN 16
V_{SS} = PIN 8

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	– 55°C		25°C			125°C		Unit
			Min	Max	Min	Typ #	Max	Min	Max	
Output Voltage "0" Level V_{in} = V_{DD} or 0	V_{OL}	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
"1" Level V_{in} = 0 or V_{DD}	V_{OH}	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage "0" Level	V_{IL}									Vdc
(V_O = 4.5 or 0.5 Vdc)		5.0	—	1.2	—	2.25	1.25	—	1.15	
(V_O = 9.0 or 1.0 Vdc)		10	—	2.5	—	4.50	2.5	—	2.4	
(V_O = 13.5 or 1.5 Vdc)		15	—	3.0	—	6.75	3.0	—	2.9	
"1" Level	V_{IH}									Vdc
(V_O = 0.5 or 4.5 Vdc)		5.0	3.85	—	3.75	2.75	—	3.75	—	
(V_O = 1.0 or 9.0 Vdc)		10	7.6	—	7.5	5.50	—	7.5	—	
(V_O = 1.5 or 13.5 Vdc)		15	12.1	—	12	8.25	—	12		
Output Drive Current	I_{OH}									mAdc
(V_{OH} = 2.5 Vdc) Source		5.0	– 3.0	—	– 2.4	– 4.2	—	– 1.7	—	
(V_{OH} = 4.6 Vdc)		5.0	– 0.64	—	– 0.51	– 0.88	—	– 0.36	—	
(V_{OH} = 9.5 Vdc)		10	– 1.6	—	– 1.3	– 2.25	—	– 0.9	—	
(V_{OH} = 13.5 Vdc)		15	– 4.2	—	– 3.4	– 8.8	—	– 2.4	—	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
(V_{OL} = 0.5 Vdc)		10	1.6	—	1.3	2.25	—	0.9	—	
(V_{OL} = 1.5 Vdc)		15	4.2	—	3.4	8.8	—	2.4	—	
Input Current	I_{in}	15	—	± 0.1	—	±0.00001	± 0.1	—	± 1.0	µAdc
Input Capacitance (V_{in} = 0)	C_{in}	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current (Per Package)	I_{DD}	5.0	—	0.25	—	0.0005	0.25	—	7.5	µAdc
		10	—	0.5	—	0.0010	0.5	—	15	
		15	—	1.0	—	0.0015	1.0	—	30	
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0	I_T = (0.75 µA/kHz) f + I_{DD}							µAdc
		10	I_T = (1.50 µA/kHz) f + I_{DD}							
		15	I_T = (2.25 µA/kHz) f + I_{DD}							

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

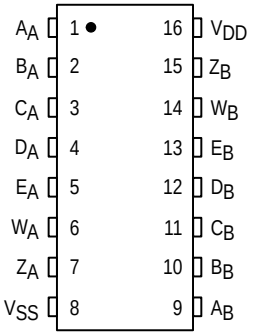
** The formulas given are for the typical characteristics only at 25°C.

* To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$$

where: I_T is in µA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.002.

PIN ASSIGNMENT



SWITCHING CHARACTERISTICS* (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD}	Min	Typ #	Max	Unit
Output Rise and Fall Time	t_{TLH},					ns
t_{TLH}, t_{THL} = (1.5 ns/pF) C_L + 25 ns	t_{THL}	5.0	—	100	200	
t_{TLH}, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns		10	—	50	100	
t_{TLH}, t_{THL} = (0.55 ns/pF) C_L + 9.5 ns		15	—	40	80	
Propagation Delay Time	t_{PLH}					ns
A, C, W = V_{DD}; B, E = Gnd; D = Pulse Generator						
t_{PLH} = (1.7 ns/pF) C_L + 290 ns		5.0	—	375	960	
t_{PLH} = (0.66 ns/pF) C_L + 127 ns		10	—	160	400	
t_{PLH} = (0.5 ns/pF) C_L + 85 ns		15	—	110	300	
t_{PHL} = (1.7 ns/pF) C_L + 345 ns	t_{PHL}	5.0	—	430	1200	ns
t_{PHL} = (0.66 ns/pF) C_L + 162 ns		10	—	195	540	
t_{PHL} = (0.5 ns/pF) C_L + 95 ns		15	—	120	410	
A, B, C, D, E = Pulse Generator; W = V_{DD}	t_{PLH}					ns
t_{PLH} = (1.7 ns/pF) C_L + 170 ns		5.0	—	255	640	
t_{PLH} = (0.66 ns/pF) C_L + 87 ns		10	—	120	300	
t_{PLH} = (0.5 ns/pF) C_L + 60 ns		15	—	86	210	
t_{PHL} = (1.7 ns/pF) C_L + 195 ns	t_{PHL}	5.0	—	280	750	ns
t_{PHL} = (0.66 ns/pF) C_L + 92 ns		10	—	125	330	
t_{PHL} = (0.5 ns/pF) C_L + 75 ns		15	—	100	250	
A, B, C, D, E = Gnd; W = Pulse Generator	t_{PLH},					ns
t_{PHL}, t_{PLH} = (1.7 ns/pF) C_L + 145 ns	t_{PHL}	5.0	—	230	575	
t_{PHL}, t_{PLH} = (0.66 ns/pF) C_L + 72 ns		10	—	105	265	
t_{PHL}, t_{PLH} = (0.5 ns/pF) C_L + 50 ns		15	—	75	190	

* The formulas given are for the typical characteristics only at 25°C.
#Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

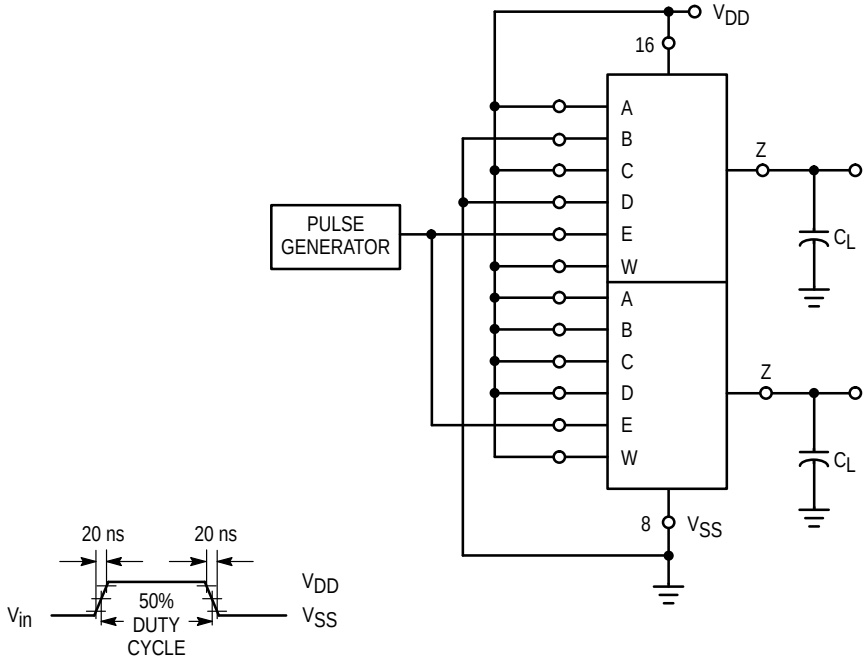
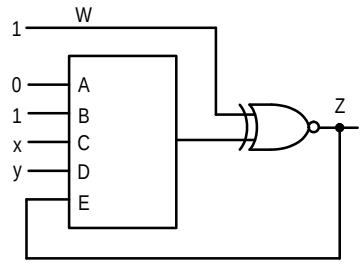


Figure 1. Power Dissipation Test Circuit and Waveform

SEQUENTIAL LOGIC APPLICATIONS

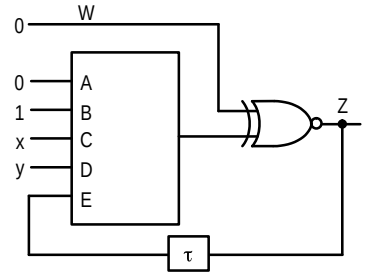
COINCIDENT FLIP–FLOP



x	y	Q_{n+1}
0	0	0
0	1	Q
0	0	Q
1	1	1

A flip–flop that will change only when both inputs agree.

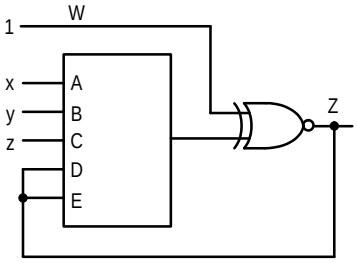
ASTABLE MULTIVIBRATOR



x	y	Q_{n+1}
0	0	1
0	1	2τ
1	0	2τ
1	1	1

A flip–flop with three output conditions, where the third state is in oscillation between “1” and “0”. The period of oscillation is twice the delay of the gate and the feedback element.

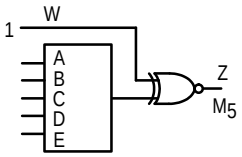
COINCIDENT FLIP–FLOP

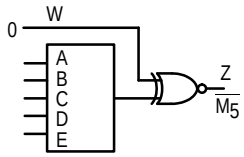


t_x	y	z	Q_{n+1}
0	0	0	0
0	0	1	Q_n
0	1	0	Q_n
0	1	1	Q_n
1	0	0	Q_n
1	0	1	Q_n
1	1	0	Qn
1	1	1	1

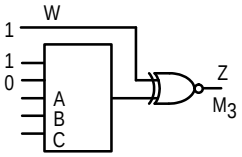
The flip–flop changes state only when all “1’s” or all “0’s” are entered. This configuration may be extended by cascading M_5 gates to cover n–inputs where all inputs must be “1’s” or “0’s” before the output will change. As an example, this configuration is useful for controlling an n–stage up/down counter that is to cycle from a minimum to maximum count and back again without flipping over (from all “1’s” to all “0’s”.)

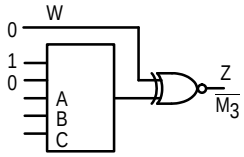
BASIC COMBINATIONAL FUNCTIONS



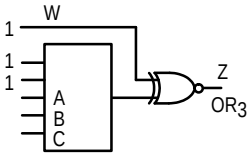


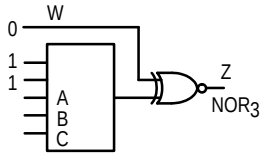
5–INPUT MAJORITY GATES





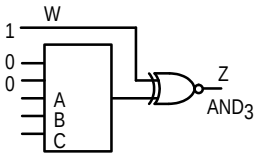
3–INPUT MAJORITY GATES

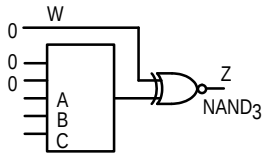




3–INPUT OR GATE

3–INPUT NOR GATE

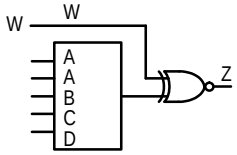




3–INPUT AND GATE

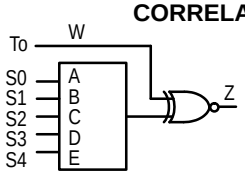
3–INPUT NAND GATE

DOUBLING THE WEIGHT OF INPUT VARIABLE A BY TYING IT TO ANY TWO INPUTS



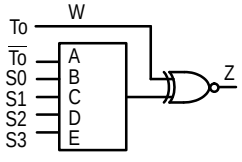
(AB + AC + AD + BCD) ⊙ W

CORRELATION OF MULTIPLE SAMPLES WITH A TEST BIT

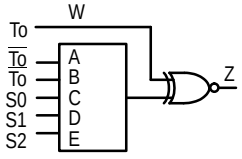


CORRELATION OF 60%, 80%, 100%

The gate will have a “1” output if the test bit To matches or correlates with 3, 4 or 5 of the sample bits S0–S4.



CORRELATION OF 75%, 100%



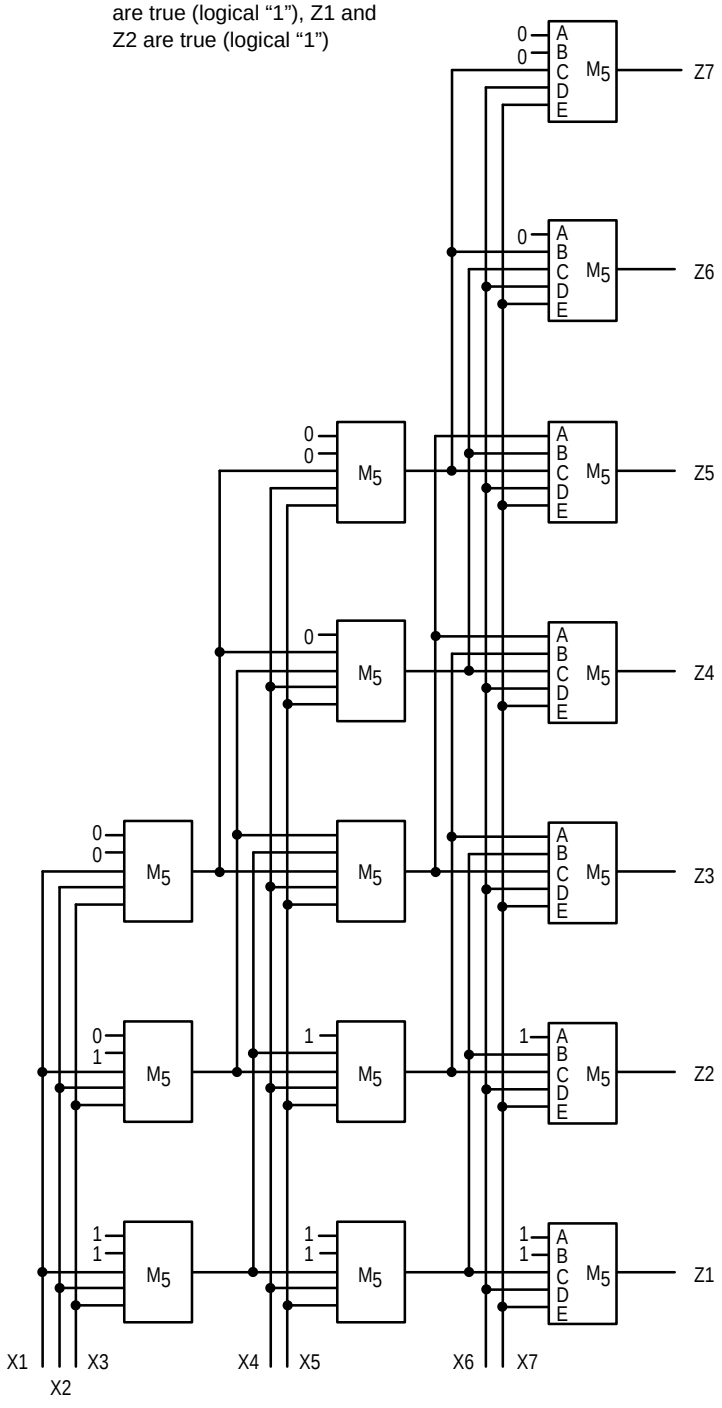
CORRELATION OF 100%

5–INPUT MAJORITY LOGIC GATE APPLICATIONS

Each package labeled M_5 is a single majority logic gate using five inputs, A thru E, and one output Z.

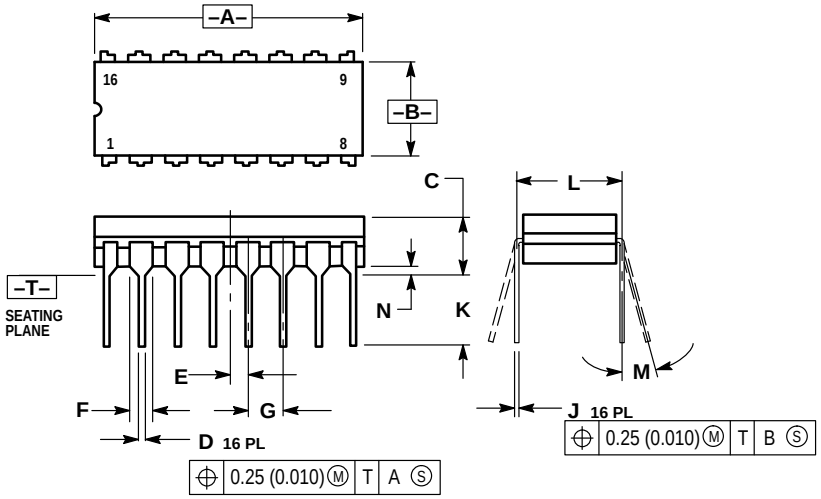
1. Majority Logic Gate Array yielding the symmetric function of 1 thru 7 variables true, out of 7 input variables (X1... X7)

   (e.g., if any two–input variables are true (logical “1”), Z1 and Z2 are true (logical “1”)



OUTLINE DIMENSIONS

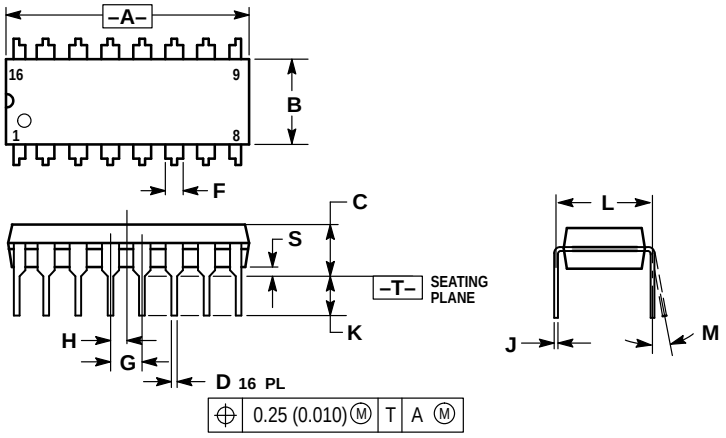
L SUFFIX
CERAMIC DIP PACKAGE
CASE 620–10
ISSUE V



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.020	0.39	0.50
E	0.050 BSC		1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100 BSC		2.54 BSC	
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300 BSC		7.62 BSC	
M	0 °	15 °	0 °	15 °
N	0.020	0.040	0.51	1.01

P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R

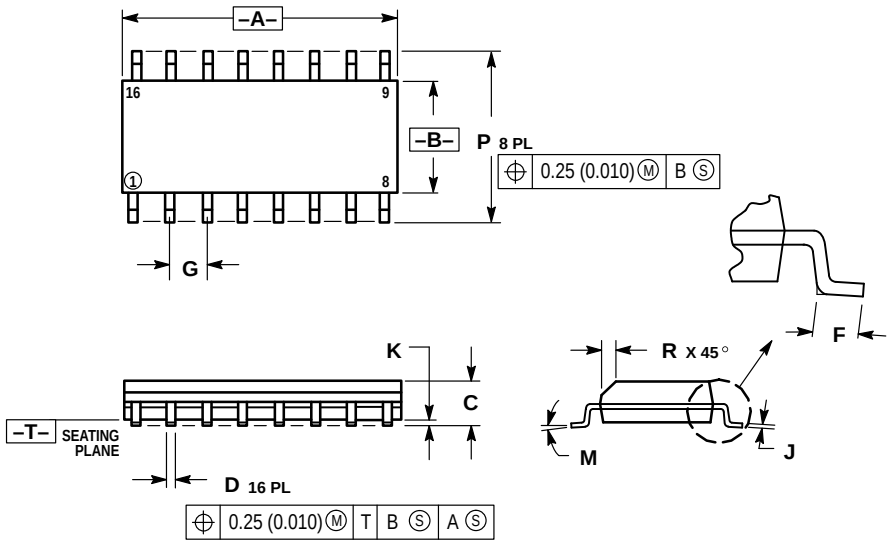


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

OUTLINE DIMENSIONS

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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